DISCRETE SEMICONDUCTORS

DATA SHEET

BGY114D; BGY114E UHF amplifier modules

Product specification Supersedes data of April 1994 File under Discrete Semiconductors, SC09 1996 Jun 04





UHF amplifier modules

BGY114D; BGY114E

FEATURES

- 12.5 V nominal supply voltage
- 6 W output power
- Easy control of output power by DC voltage.

APPLICATIONS

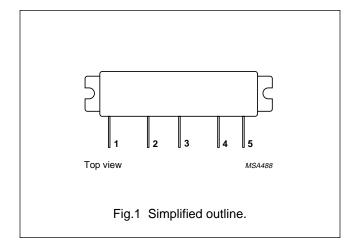
 Personal Mobile Radio (PMR) equipment operating in the 800 to 870 MHz and 890 to 950 MHz frequency ranges.

DESCRIPTION

The BGY114D and BGY114E are five-stage UHF amplifier modules in a SOT278A package. Each module consists of 5 NPN silicon planar transistor dies mounted together with matching and bias circuit components on a metallized ceramic substrate.

PINNING - SOT278A

PIN	DESCRIPTION
1	RF input
2	V _{S1}
3	V _C
4	V _{S2}
5	RF output
Flange	ground



QUICK REFERENCE DATA

RF performance at $T_{mb} = 25$ °C.

TYPE NUMBER	MODE OF OPERATION	f (MHz)	V _{S1} (V)	V _{S2} (V)	P _L (W)	G _p (dB)	η (%)	Z _S ; Z _L (Ω)
BGY114D	CW	800 to 870	8	12.5	6	≥37.8	typ. 40	50
BGY114E	CW	890 to 950	8	12.5	6	≥37.8	typ. 40	50

WARNING

Product and environmental safety - toxic materials

This product contains beryllium oxide. The product is entirely safe provided that the BeO disc is not damaged. All persons who handle, use or dispose of this product should be aware of its nature and of the necessary safety precautions. After use, dispose of as chemical or special waste according to the regulations applying at the location of the user. It must never be thrown out with the general or domestic waste.

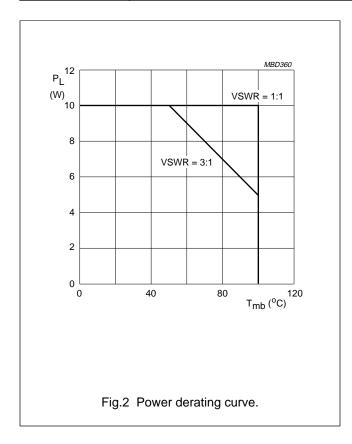
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LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V _{S1}	DC supply voltage	_	9	V
V _{S2}	DC supply voltage	_	16	V
V _C	DC control voltage	_	9	V
P _D	input drive power	_	3	mW
PL	load power	_	10	W
T _{stg}	storage temperature	-40	+100	°C
T _{mb}	operating mounting base temperature	-30	+100	°C



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CHARACTERISTICS

 $Z_S = Z_L = 50~\Omega;~P_D = 1~mW;~V_{S1} = 8~V;~V_{S2} = 12.5~V;~V_C \leq 8~V;~T_{mb} = 25~^{\circ}C;~unless~otherwise~specified.$

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
f	frequency					
	BGY114D		800	_	870	MHz
	BGY114E		890	_	950	MHz
I _{Q3}	leakage current	$V_{S1} = V_C = 0; P_D = 0$	_	_	1	mA
P _L	load power		6	_	_	W
G _p	power gain	adjust V _C for P _L = 6 W	37.8	_	_	dB
η	efficiency	adjust V _C for P _L = 6 W	30	40	_	%
H ₂	second harmonic	adjust V _C for P _L = 6 W	_	_	-35	dBc
H ₃	third harmonic	adjust V _C for P _L = 6 W	_	_	-35	dBc
VSWRin	input VSWR	adjust V _C for P _L = 6 W	_	_	3:1	
ΔG	gain control	V _C = 0 to 8 V	30	_	_	dB
	stability	$P_D = -3 \text{ to } +3 \text{ dBm}; V_{S2} = 10 \text{ to } 16 \text{ V};$ $V_C = 0 \text{ to } 8 \text{ V}; P_L \le 7 \text{ W}; VSWR \le 3 : 1$	_	_	-60	dBc
	ruggedness	V_{S2} = 16 V; $P_L \le 7$ W, duration 1 minute; VSWR ≤ 20 : 1	no degradation			

List of components (see Fig.3)

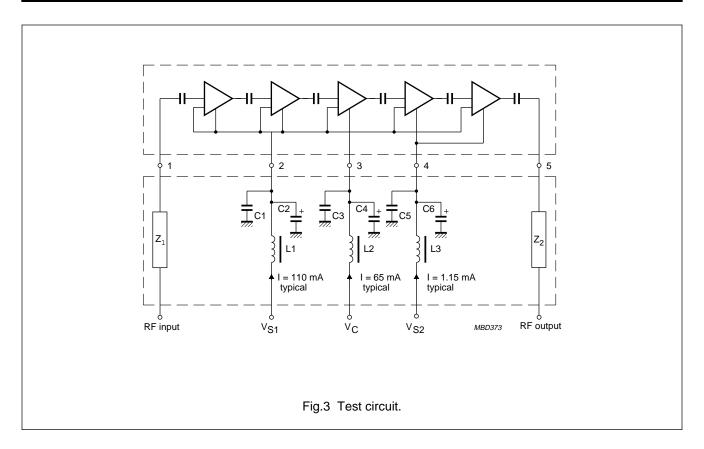
COMPONENT	DESCRIPTION	VALUE	DIMENSION	CATALOGUE NO.
C1, C3, C5	multilayer ceramic chip capacitor; note 1	1 nF	_	_
C2, C4, C6	tantalum capacitor	1 μF; 35 V	_	_
L1, L2, L3	Ferroxcube chip bead; grade 4S2	_	_	4330 030 36300
Z ₁ , Z ₂	stripline; note 2	50 Ω	width 4.7 mm	_

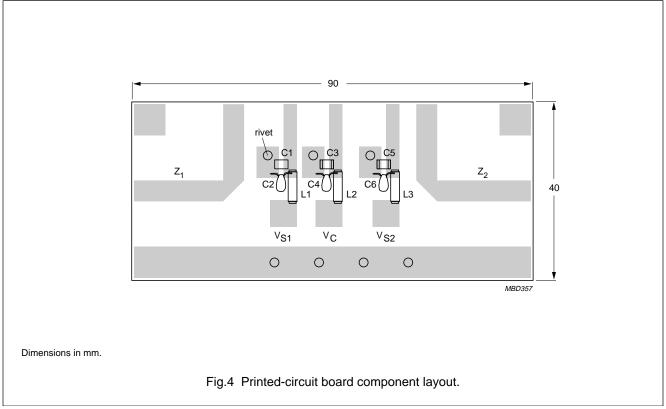
Notes

- 1. ATC capacitor type 100B or capacitor of same quality.
- 2. The striplines are on a double copper-clad printed-circuit board with PTFE fibre-glass dielectric (ϵ_r = 2.2); thickness 1/16 inch.

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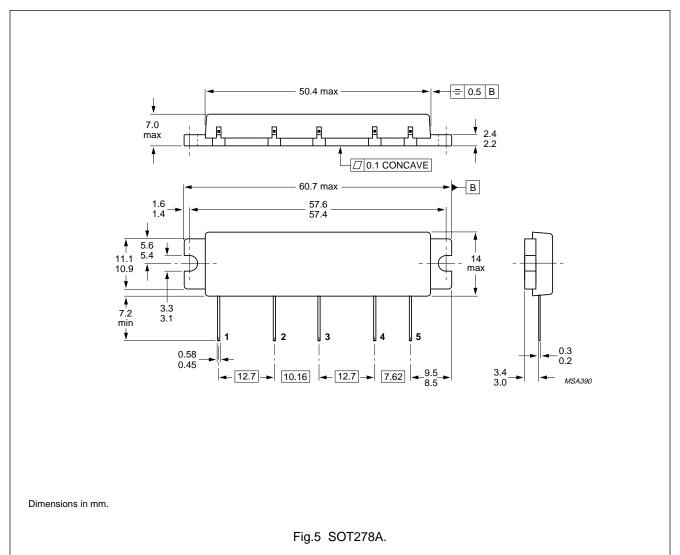




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PACKAGE OUTLINE



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DEFINITIONS

Data Sheet Status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	

Limiting values

Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.